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October 2013

FDP2710

N-Channel PowerTrench® MOSFET 250 V, 50 A, 42.5 m Ω

Features

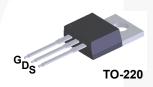
- $R_{DS(on)}$ = 36.3 m Ω (Typ.)@ V_{GS} = 10 V, I_D = 25 A
- · Fast Switching Speed
- · Low Gate Charge
- High Performance Trench technology for Extremely Low $R_{\text{DS(on)}}$
- · High Power and Current Handing Capability
- · RoHS Compliant

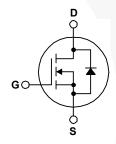
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- · Consumer Appliances
- · Synchronous Rectification





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			FDP2710	Unit	
V _{DS}	Drain-Source Voltage			250	V	
V _{GS}	Gate-Source voltage			± 30	V	
I _D	Drain Current	- Continuous (T _C = 25° - Continuous (T _C = 100	,	50 31.3	A A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	See Figure 9	A	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	145	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	4.5	V/ns	
P_{D}	Power Dissipation (T _C = 25°C) - Derate above 25°C			260 2.1	W W/°C	
T _{J,} T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		pose,	300	°C	

Thermal Characteristics

Symbol	Parameter	FDP2710	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.48	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP2710	FDP2710	TO-220	Tube	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Off Charac	Off Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V$, $I_D = 250\mu A$, $T_J = 25^{\circ}C$	250			V	
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		0.25		V/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 250V, V _{GS} = 0V V _{DS} = 250V, V _{GS} = 0V, T _C = 125°C			10 500	μA μA	
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30V, V _{DS} = 0V			100	nA	
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30V, V _{DS} = 0V			-100	nA	
On Charac	teristics				_		
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0	4.0	5.0	V	
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 25A		36.3	42.5	mΩ	
9 _{FS}	Forward Transconductance	V _{DS} = 10V, I _D = 25A		63		S	
Dynamic C	Characteristics					•	
C _{iss}	Input Capacitance		\	5470	7280	pF	
C _{oss}	Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz		426	570	pF	
C _{rss}	Reverse Transfer Capacitance	1 = 1.0WH2		97	146	pF	
Switching	Characteristics						
t _{d(on)}	Turn-On Delay Time			80	170	ns	
t _r	Turn-On Rise Time	$V_{DD} = 125V, I_D = 50A$ $V_{GS} = 10V, R_{GEN} = 25\Omega$		252	515	ns	
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, N _{GEN} = 2352		112	235	ns	
t _f	Turn-Off Fall Time	(Note 4)		154	320	ns	
Qg	Total Gate Charge			78	101	nC	
Q _{gs}	Gate-Source Charge	$V_{DS} = 125V, I_D = 50A$ $V_{GS} = 10V$	-	34		nC	
Q _{gd}	Gate-Drain Charge	(Note 4)	/	18		nC	
Drain-Sour	rce Diode Characteristics and Maximun	n Ratings		l		ı	
I _S	Maximum Continuous Drain-Source Diode Forward Current				50	Α	
I _{SM}	Maximum Pulsed Drain-Source Diode Fo	orward Current			150	Α	
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0V, I _S = 50A			1.2	V	
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 50A		163		ns	
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100A/μs		1.3	/	μС	

Notes

^{1.} Repetitive Rating: Pulse width limited by maximum junction temperature

^{2.} L = 1mH, I_{AS} = 17A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}$ C

^{3.} I $_{SD} \le 50 \text{A}, \text{ di/dt} \le 100 \text{A/}\mu\text{s}, \text{ V}_{DD} \le \text{BV}_{DSS}, \text{ Starting T}_J = 25^{\circ}\text{C}$

^{4.} Essentially Independent of Operating Temperature Typical Characteristics

Typical Performance Characteristics

Figure 1. On-Region Characteristics

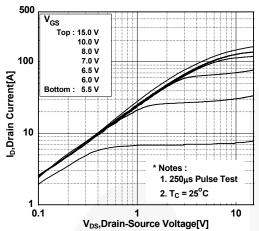


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

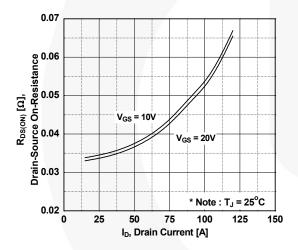


Figure 5. Capacitance Characteristics

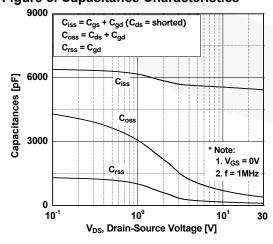


Figure 2. Transfer Characteristics

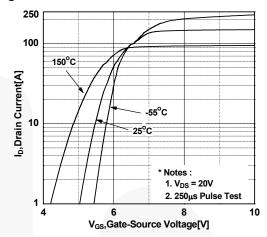


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

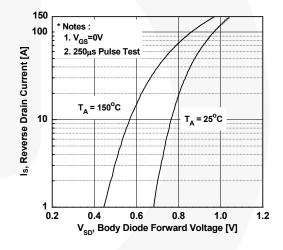
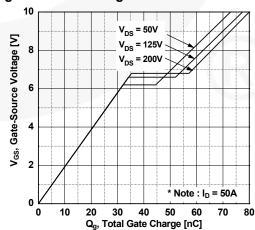


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

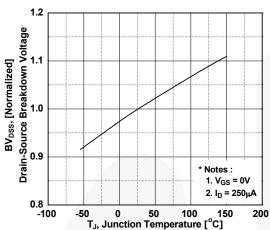


Figure 9. Maximum Safe Operating Area

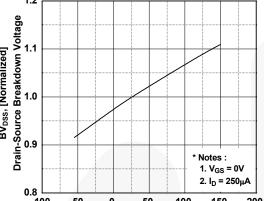


Figure 8. On-Resistance Variation vs. Temperature

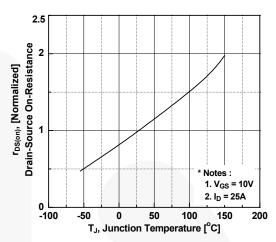
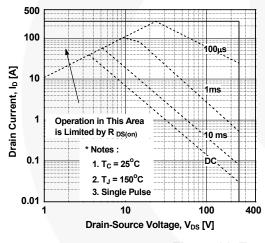


Figure 10. Maximum Drain Current vs. Case Temperature



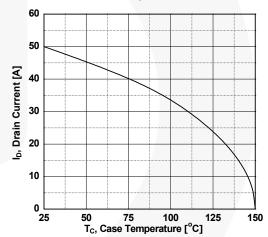


Figure 11. Transient Thermal Response Curve

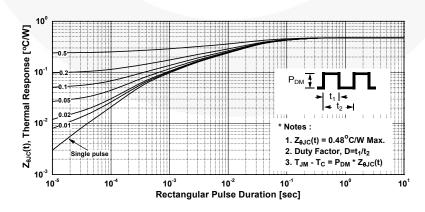


Figure 12. Gate Charge Test Circuit & Waveform

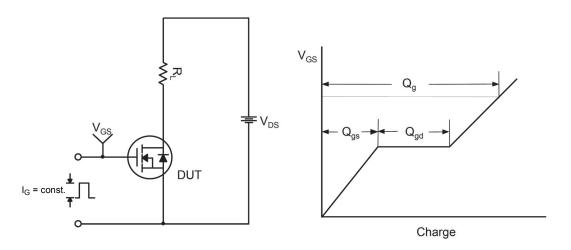


Figure 13. Resistive Switching Test Circuit & Waveforms

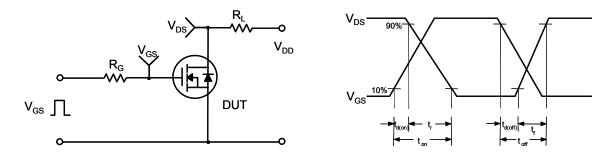
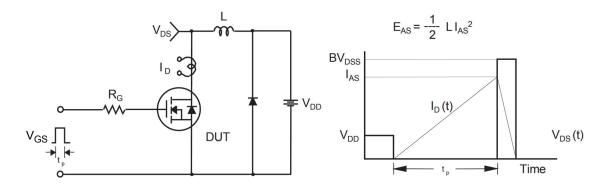


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



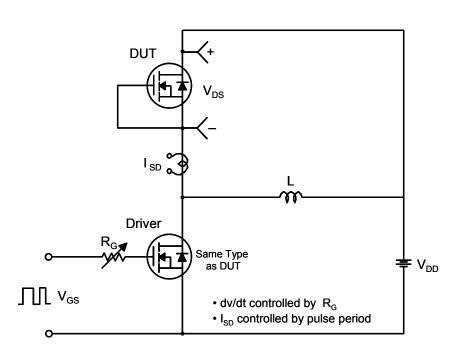
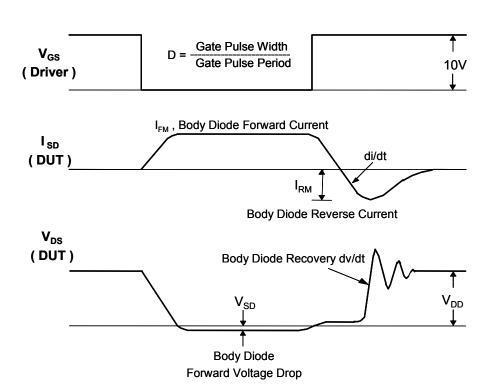


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



Mechanical Dimensions

TO-220 3L

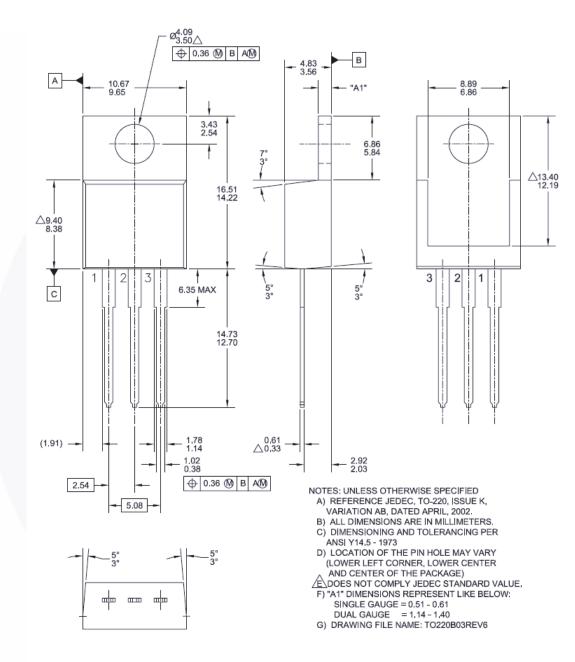


Figure 16. TO-220, Molded, 3Lead, Jedec Variation AB

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Dimension in Millimeters





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